SCAS023A - D2957, JULY 1978 - REVISED APRIL 1993

- Compares Two 8-Bit Words
- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes
 PCB Layout
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Plastic Shrink Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

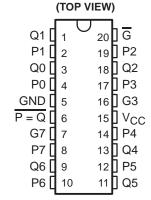
These identity comparators perform comparisons on two 8-bit binary or BCD words. Also included is a $\overline{P} = \overline{Q}$ totem-pole output.

The 54ACT11521 is characterized for operation over the full military temperature range of -55° C to 125°C. The 74ACT11521 is characterized for operation from -40° C to 85° C.

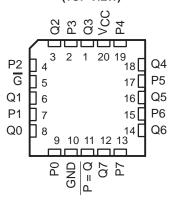
FUNCTION TABLE

INF	OUTPUT				
DATA P, Q	ENABLE G	P = Q			
P = Q	L	L			
P > Q	L	Н			
P < Q	L	Н			
Х	Н	Н			

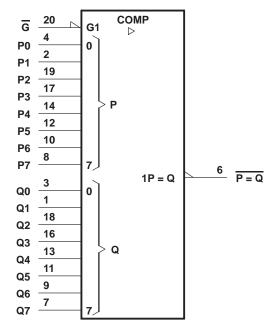
54ACT11521 . . . J PACKAGE 74ACT11521 . . . DB, DW OR N PACKAGE



54ACT11521 . . . FK PACKAGE (TOP VIEW)

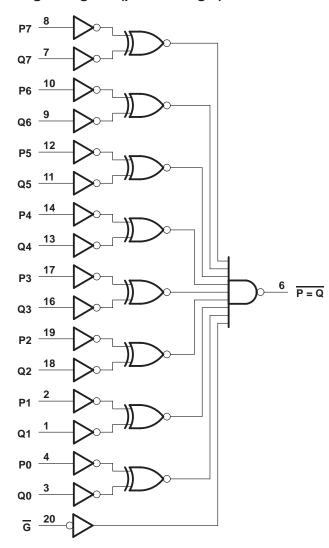


logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



Pin numbers shown are for the DW, J, and N packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	0.5 V to 6 V
Input voltage range, V _I (see Note 1)	-0.5 V to $V_{CC} + 0.5 \text{ V}$
Output voltage range, V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	± 20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	$ \pm 50 \text{ mA}$
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	
Continuous current through V _{CC} or GND	± 100 mA
Storage temperature range	

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



recommended operating conditions

		54ACT11521			74ACT11521			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNII	
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V	
VIH	High-level input voltage	2			2			V	
V _{IL}	Low-level input voltage			0.8			0.8	V	
VI	Input voltage	0		VCC	0		VCC	V	
Vo	Output voltage	0		VCC	0		VCC	V	
loh	High-level output current			-24			-24	mA	
loL	Low-level output current			24			24	mA	
Δt/Δν	Input transition rise or fall rate	0		10	0		10	ns/V	
T _A	Operating free-air temperature	-55		125	-40		85	°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A = 25°C			54AC	Γ11521	74ACT11521		UNIT	
		vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
^V ОН	I _{OH} = - 50 μA	4.5 V	4.4			4.4		4.4		· v	
		5.5 V	5.4			5.4		5.4			
	I _{OH} = – 24 mA	4.5 V	3.94			3.7		3.8			
		5.5 V	4.94			4.7		4.8			
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85					
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V						3.85			
	ΙΟL = 50 μΑ	4.5 V			0.1		0.1		0.1	V	
		5.5 V			0.1		0.1		0.1		
V	I _{OL} = 24 mA	4.5 V			0.36		0.5		0.44		
V _{OL}		5.5 V			0.36		0.5		0.44		
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V					1.65				
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V							1.65		
ΙĮ	V _I = V _{CC} or GND	5.5 V			± 0.1		± 1		±1	μΑ	
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			8		160		80	μΑ	
∆lcc‡	One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V			0.9		1		1	mA	
C _i	$V_I = V_{CC}$ or GND	5 V		4						pF	

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT) (OI	ТО	T _A = 25°C			54ACT11521		74ACT11521		UNIT
		(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	P or Q	$\overline{P} = Q$	1.5	8.8	13	1.5	15.9	1.5	14.7	ns
^t PHL	PorQ		1.5	8.2	12	1.5	14.6	1.5	13.6	
t _{PLH}	\overline{G} $\overline{P} = \overline{Q}$	1.5	6.7	9.3	1.5	11.2	1.5	10.5		
tPHL	9	G P = Q	1.5	6.8	8.8	1.5	10.2	1.5	9.7	ns

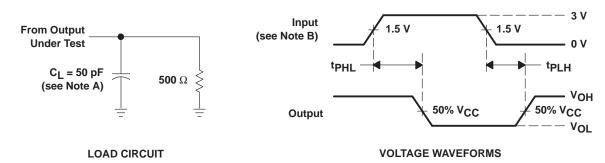
[‡] This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

SCAS023A - D2957, JULY 1978 - REVISED APRIL 1993

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	40	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f = 3$ ns. $t_f = 3$ ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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